Coulom b crystallization in two-component plasm as

M.Bonitz¹, V.S.Filinov^{1,2}, V.E.Fortov², P.R.Levashov², and H.Fehske³

¹Institut fur Theoretische Physik und Astrophysik,

Christian – Albrechts-Universitat zu Kiel, Leibnizstr. 15, 24098 Kiel, Germany

² Institute for H igh Energy D ensity, Russian A cadem y of Sciences, Izhorskay 13/19, M oscow 127412, Russia and

³ Institut fur Physik, Emst-Moritz-Amdt-Universitat Greifswald, Domstrasse 10a, D-17489 Greifswald, Gemany

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The analysis of C oulom b crystallization is extended from one-component to two-component plasmas. C ritical parameters for the existence of C oulom b crystals are derived for both classical and quantum crystals. In the latter case, a critical mass ratio of the two charged components is found which is of the order of 80. Thus, holes in semiconductors with su ciently at valence bands are predicted to spontaneously order into a regular lattice. Such hole crystals are intim ately related to ion C oulom b crystals in white dwarf and neutron stars as well as to ion crystals produced in the laboratory. A uni ed phase diagram of two-component C oulom b crystals is presented and is veried by rst-principle computer simulations.

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Crystallization is one of the most fundam ental manyparticle phenom ena in charged particle system s. A fter the prediction of a highly correlated state of the electron gas { the electron W igner crystal [1] { there has been an active search for this phenom enon in many elds. Crystallization of electrons was observed on the surface of helium droplets [2] and is predicted to occur in sem iconductor quantum dots [3]. Moreover, crystals of ions have been observed in traps [4] and storage rings [5], and are expected to occur in layered system s [6]. The necessary condition for the existence of a crystal in these onecom ponent plasm as (OCP) is that the mean Coulom b interaction energy, $e^2 = r$ (r denotes the m can inter-particle distance), exceeds the mean kinetic energy (therm al energy $\frac{3}{2}k_{\rm B}T$ or Fermienergy $E_{\rm F}$ in classical or quantum plasmas, respectively) by a factor larger than ^{cr} which, in a classical OCP is given by 175 [2,7]. In a quantum OCP at zero tem perature the coupling strength is m easured by the Brueckner parameter, r_s $r=a_B$ (a_B denotes the e ective Bohr radius), with a critical value for crystallization of r_s^cr 100 [8].

The vast majority of Coulomb matter in the Universe, how ever, exists in the form of neutral plasm as, containing (at least) two oppositely charged components (twocomponent plasm a, TCP). Coulom b crystallization in a TCP has been observed as well, e.g. in colloidal and dusty plasm as [9, 10] and it is predicted to be possible in laser-cooled expanding plasm as [11]. The lattice of heavy particles is immersed into a structureless gas of the light component which does not a ect the form er. Besides these classical TCP crystals it is expected that in the interior of white dwarf stars and in the crust of neutron stars there exists an entirely di erent type of TCP crystals [12]: Crystals of highly charged ions (e.g. fully ionized carbon, oxygen, iron) which are embedded into an extrem ely dense degenerate Ferm i gas of electrons. No such quantum TCP crystals have been observed in the laboratory, despite early suggestions [13]. It is an open question what classical and quantum TCP crystals (being separated by 15:::20 orders of m agnitude in density) have in common and if there exists an integrative phase diagram.

This Letter aims to answer these questions. We show that, in fact, a common phase diagram of C oulomb crystals in a generic neutral TCP (consisting of electrons and point-like ions [14]) exists which is governed by ve parameters { density and temperature (as in the OCP case) and, additionally, by the asymmetry of the heavy (h) and electron (e) components with respect to three fundamental properties: M ass, charge and temperature, $M = m_h = m_e$, $Z = Z_h = Z_e$ and $= T_e = T_h$. We show that classical TCP crystals require a critical charge ratio Z whereas quantum TCP crystals exist only if the mass ratio M exceeds a critical value of about 80. As a consequence, we predict the existence of quantum TCP crystals of protons in a dense hydrogen plasm a and crystals of holes in sem iconductors.

Let us consider a locally neutral system of electrons and Z-fold charged heavy particles. The stationary state of the TCP is characterized by the dimensionless electron temperature $T_e=3k_B\,T=\!2E_B$ and mean inter-electron distance $r_{\rm se}$ = $r_e=\!a_B$, where E_B denotes the e-h binding energy, and the dimensionless density is given by na_B^3 = $3=(4\ r_{\rm se}^2)$.

C lassical crystal. For the existence of a C oulom b crystal in the presence of a classical gas of electrons, we rst require that the heavy component is able to form a classical O C P crystal, i.e.

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and, secondly, that the electrons do not destroy that crystal, e.g., as a result of screening of the heavy particle interaction. However, the main obstacle for the crystal turns out to be the formation of e-h bound states (atom s, excitons etc.), because this drastically reduces the h-h correlation energy causing violation of condition (1). Therefore, we require that no signi cant fraction of heavy particles is trapped in C oulom b bound states, for which a conservative estimate is given by T_e 1, stating that the electrons have su ciently high kinetic energy to escape the binding potential V_{eh} . Making use of charge neutrality, $n_e = n_h Z$, and the denitions of and T_e we not from Eq. (1) that the classical TCP C oulomb crystal exists between the temperatures $T_e^{(1)}$ and $T_e^{(2)}$, given by

$$T_{e}^{(1)}$$
 1 and $T_{e}^{(2)}(r_{se}) = \frac{3 Z^{2=3}}{cr} \frac{1}{r_{se}}$; (2)

and only if the ion charge exceeds a critical value, Z_e^{cr} (;r_{se}) = (${}^{cr}r_{se}$ =3) ${}^{3=2}$, which is independent of the mass ratio M .

Quantum TCP crystal and critical mass ratio. In the presence of quantum electrons, the condition for crystallization of the heavy particles follows from the quantum OCP result, $r_{\rm sh} = r_{\rm s}^{\rm cr}$. To be specific, we will concentrate on hydrogen-like C oulomb bound states, where $E_{\rm B} = \frac{Z\,e^2}{4} \frac{1}{0} \frac{1}{r^2 2a_{\rm B}}$, and $a_{\rm B} = \frac{h^2}{m_{\rm r}} \frac{4}{2} \frac{0}{e^2} r$ [r and mr are the background dielectric constant and the reduced mass $m_{\rm r}^{-1} = m_{\rm h}^{-1}$ (1 + M)]. Since $r_{\rm s}^{\rm cr}$ refers to the critical interparticle distance in units of the hydrogenic $a_{\rm B}^{\rm H}$ [B], we rst transform to the relevant electrice Bohr radius $a_{\rm B}$. Further, we eliminate $r_{\rm sh}$ by expressing $r_{\rm h}$ by $r_{\rm e}$ using again charge neutrality. Then the OCP result can be rewritten as

$$Z^{4=3} (M + 1)r_{se} r_{s}^{cr}$$
: (3)

This crystal of heavy particles will survive in the presence of electrons only if, as in the classical case, bound states are unstable which, at zero tem perature, occurs due to pressure ionization at densities above the M ott density, i.e. $r_{\rm se} ~ r_{\rm s}^{\rm M \ ott} ~ 1.2$ (see below). W ith increasing tem – perature, ionization becomes possible at lower density which we indicate by a monotonically decreasing function $1 = r_{\rm s}^{\rm M \ ott} ~ (T_{\rm e})$ which vanishes when $T_{\rm e}$! 1 because there there alionization prevails. C on bination of (3) with the existence of pressure ionization allows us to elim inate $r_{\rm se}$, yielding the criterion for the existence of a TCP crystal in the presence of a neutralizing background of quantum electrons as

M M^{cr}(Z;T_e) =
$$\frac{r_s^{cr}}{Z^{4=3} r_s^{M \text{ ott}}(T_e)}$$
 1; (4)

which exists in a nite electron density range between

$$n^{(1)}(T_{e}) = \frac{3}{4} \frac{1}{r_{s}^{M \text{ ott}}(T_{e})}^{3}; n^{(2)}(T_{e}) = n^{(1)}(T_{e})K^{3};$$
$$K = (M + 1) = (M^{cr} + 1);$$
(5)

and below a critical tem perature T . The density limits follow from the M ott criterion and from Eq. (3), whereas T is estimated [3] by the crossing point of the classical and quantum asymptotics of an OCP crystal (1) and (3)

$$\Gamma = 6 \frac{Z^2 (M + 1)}{\operatorname{cr} r_{s}^{cr}} :$$
 (6)

In absolute units, the density intervalscales as Z³ and the critical tem perature as M Z^4 . The critical mass ratio for singly charged ions in an isothermal TCP (= 1) equals 83 and decreases with increasing tem perature (due to the lower M ott density) and with increasing Z.

Examples (= 1). (i) For a crystal of C $^{6+}$ [O $^{8+}$] ions expected to exist in the interior of white dwarf stars, the minimum density is given by $n_e^{(1)}(0) = 2$ 10⁶ cm³ 10^{6} cm³], and T = 10^{9} K [4:2 10K] [15]. (ii) [6**:**6 Hydrogen and helium are predicted to form crystals as well: A crystal of protons [particles] is stable between $n_{e}^{(1)}(0) = 0.9 \quad 10^{4} \text{ cm}^{3} [7.5 \quad 10^{4} \text{ cm}^{3}] \text{ and } n_{e}^{(2)}(0) =$ 10^{28} cm³ [5 10^{0} cm³], and below T = 6:6 10K [4:2 16K] and should be achievable in laboratory experim ents with laser or ion beam com pression techniques. (iii) C rystallization of holes in sem iconductors (Z = 1) is predicted form aterials with a hole to electron m ass ratio М M ^{cr} 83 [16]. This value is feasible in intermediate valence sem iconductors, such as Tm [Se,Te] [17]. For example, for M = 100 (using r = 20) the parameters $\operatorname{aren}_{e}^{(1)}(0) = 12$ 10° cm³, $n_{e}^{(2)}(0) = 21$ 10° cm³ and т

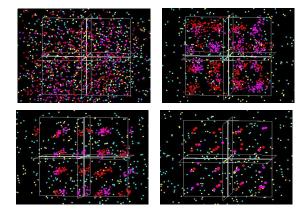


FIG.1: Snapshots of an e-h plasma at $T_e = 0.096$, and $r_{se} = 0.63$. Clouds of blue (yellow) dots mark the fully delocalized electrons with spin up (down), clouds of red (pink) dots denote holes with spin up (down). Top left (right): M = 5 (50), bottom left (right): M = 100 (800).

Num erical veri cation. O fcourse, the boundary of the TCP crystalphase at low densities contains som e uncertainty, due to the very com plex transition from an atom ic system to a Coulomb crystal of heavy particles embedded into delocalized electrons. This transition which extends over a nite density interval may involve liquidlike behavior, clusters and, at low temperature, phase separation, an analysis of which is beyond the present study. We estim ate that these e ects give rise to an uncertainty of the minimum density (M ott density), n⁽¹⁾, of the order of 30% . Further, the error of r_s^{cr} is about 20% [8], thus the critical param eters carry an uncertainty of about 50% . For particular system s, more accurate predictions are possible if the M ott parameter $r_{\rm s}^{\rm M \ ott}$ is known, e.g. from computer simulations. Note that the com plex processes of interest pose an extrem e challenge to the simulations: They must self-consistently include the full C oulom b interactions, e-h bound state form ation in the presence of a surrounding plasma, pressure ionization and the quantum and spin properties of the light and heavy species.

W e therefore have perform ed extensive direct ferm ionic path integral Monte Carlo (PIMC) simulations of electron-hole plasm as which are based on our previous results for dense hydrogen-helium plasm as [18], e-h plasm as [19] and electron W igner crystallization [3]. W hile the so-called sign problem prohibits PIMC simulations of the ground state of a ferm ion system, here we restrict ourselves to tem peratures at the upper boundary of the hole crystalphase, i.e. $T_e = 0.06 ::: 0.2$. Studying m ass ratios in the range of M = 1 ::: 2000 and densities corresponding to $r_{se} = 0.6$:::13 the simulations cover a large variety of C oulom b system s { from positronium, over typical sem iconductors to hydrogen. W e start with the case of low densities (large r_{se}) to determ ine the M ott density n⁽¹⁾. Here the TCP consists of excitons and biexcitons, and we found [20] that for $r_{\rm se}$ 12 less than 10% of the electrons and holes are bound, approving the choice ofr^M_s ott m ade above. Thus crystallization should becom e possible. This is con med by our simulations, see Figs. 1 and 2, showing results for $r_{se} = 0.63$ and di erent m ass ratios M . Fig. 1 displays snapshots of the e-h system in the simulation box. In all gure parts, the electrons form a nearly hom ogeneous Ferm i gas { individual electrons penetrate each other, extending far beyond the main sim ulation cell (shown by the grey grid lines). At the same time, the hole arrangement changes dram atically. While, at M = 5, the holes are in a gas-like state (sim ilar to the electrons), at M = 50 their structure resembles a liquid and, at M = 100 and 800, they are periodically arranged in space. Thus, between M = 100 and 50 the holes crystallize. The gure also clearly shows the mechanism of this quantum melting process: W ith reduction of M the individual hole wave functions grow continuously until, at $M = M^{cr}$, they exceed a critical size which allows for tunneling between lattice sites giving rise to hole delocalization, i.e. crystal melting. Vice versa, increase of M reduces the spatial extension of each hole which stabilizes the crystal (at M = 800, they shrink to a dot, see Fig.1).

The crystallization transition is further supported by the behavior of the pair distribution functions, g_{ab} , show n in Fig. 2. At M 50 (upper two panels) the h-h functions (black curves) has only a single peak like in a liquid. However, for M = 100, g_{hh} exhibits periodic oscillations with a deep rst minimum, typical for a crystal. The crystal exists only at low tem perature, an increase of T by a factor of 2 (from the lower right gure to the lower left) causes therm alm elting. Further, the e-e and e-h pair distributions allow us to understand the behavior of the electrons: In the hole crystal phase the electrons exhibit periodic density m odulations indicating the form ation of B loch waves (band structure) with increased concentration at distances sm aller than $0.5a_B$. Finally, we com-

puted the relative distance uctuations of the holes as a function of m ass ratio at $T_e = 0.64$ and $r_{se} = 0.63$. They show a strong increase around M = 80 :::100 typical for a solid-liquid transition (not displayed).

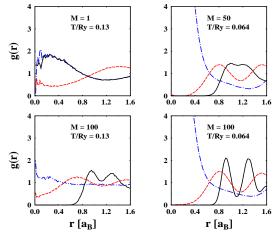


FIG.2: (Color online) e-e (blue, dash-dots), h-h (black, full line) and e-h (red, dotted line) pair distribution functions for di erent m ass ratios and tem peratures.

Phase diagram . We now construct the generic phase diagram of the TCP which applies to all the di erent Coulomb crystals, see Fig. 3. Consider 1st the case of a hole crystal in sem iconductors which is embedded into a dense Fermigas of electrons. The holes behave classically above the black dotted line and quantum m echanically below (this line is given by $n_h = 1$, where $h = h = 2 m_h k_B T_h$ is the hole deB roglie wave length). The e-h bound state phase is shown in the left part and contains excitons and biexcitons and, eventually at low tem perature, a Bose condensate, super uid or an excitonic insulator [17]. On leaving this phase across its boundary (given by the blue line $r_{se}(T_e) = r_s^{M \text{ ott}}(T_e)$) the fraction of bound states rapidly vanishes in favor of unbound e-h pairs with the holes showing liquid-like behavior. Upon further compression (at temperatures $T_e < T$) the hole liquid crystallizes, provided M M cr. At the density n⁽²⁾ quantum melting of the crystal is observed (vertical dashed green line). The entire hole Coulom b crystal phase for M = 200 is marked by the full red line in Fig. 3.

Now, how is the hole crystal in sem iconductors related to the C oulom b crystals in classical and astrophysical plasm as mentioned in the introduction? To answer this question we investigate the dependence of the stability of the crystal phase on the three asymmetry parameters. W hen M is reduced the crystal phase shrinks (see the red dashed line corresponding to M = 100) until for $M = M^{cr}$ it vanishes. V ice versa, when M becomes larger, both maximum density and tem perature at which crystallization is possible, increase according to Eqs. (5, 6). W hile in sem iconductors in quasi-equilibrium M is the only parameter which can be varied from one material to another, the diversity of ionic plasmas, on the other hand, o ers additionally control of the charge and

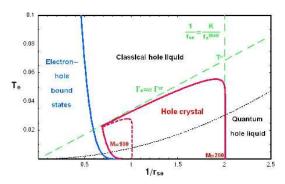


FIG. 3: (Color online) Phase diagram of a two-component plasm a in the plane of dimensionless electron temperature T_e and density parameter $1=r_{se}$. The blue line indicates the boundary of the Coulom b bound state phase given by $r_s^{\rm M}$ ^{ott} (T_e). Above (below) the dotted black line holes are classical (degenerate). The red full (dashed) line is the boundary of the hole crystal for = Z = 1 and M = 200 (M = 100) with the asymptotics given by Eqs. (1,5) (green dashed lines).

tem perature ratios Z and in very broad ranges. By increasing M, Z and the crystalphase extends further towards higher density and tem perature covering an ever increasing part of the tem perature-density plane (with the exception of the bound state phase). Eventually this crystal phase will overlap with the known classical and astrophysical C oulom b crystals at low and high densities, respectively. Thus, indeed, the phase diagram in Fig. 3 applies to all C oulom b crystals in two-com ponent plasm as of electrons and point-like ions, independently of their physical origin. O f course, in di erent system s speci c additional factors may exist. For exam ple, phase separation or non-C oulom bic bound states will modify the boundary of the bound state phase and the value

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of n⁽¹⁾, whereas band structure e ects or extended ionic cores can modify the high-density behavior [15]. Finally, while our analytical results for the crystal phase are obtained neglecting e-h correlations (which is justiled by the largem ass ratio M), the simulations indicate that the electrons have a stabilizing in uence, increasing the m aximum temperature beyond T. These e ects are beyond the present investigation and will be discussed elsew here.

In summary, one of the most fundamental collective properties of matter { Coulom b crystallization has been extended from the OCP model to the case of neutral system s with two oppositely charged components. Our analysis provides a common view and general quantitative bounds on the critical parameters for the existence of Coulom b crystals in a large variety of TCP, including dwarf stars, laser-cooled expanding plasm as, dusty plasm as and sem iconductors. The critical param eters depend on the combined mass, charge and temperature asymmetry between the heavy and light component. Crystallization of protons and of holes in sem iconductors is predicted. Hole crystals should exist in materials with a mass ratio of about 80 [21] and might be observable in rare earth sem iconductors in neutron scattering experim ents. These hole crystals could serve as a valuable testing ground for quantum TCP crystals in general and for ion crystals in exotic stellar objects in particular.

A cknow ledgm ents

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by simulations.

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